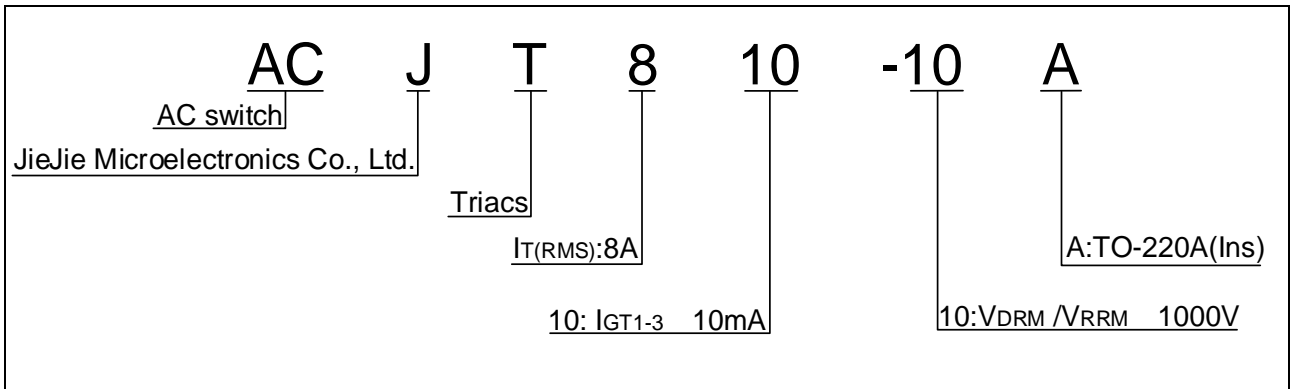




# ACJT810-10A

Average gate power dissipation ( $T_j=125$ )	$P_{G(AV)}$	0.5	W
Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive, off-state; FIG.7)	$V_{pp}$	2	kV

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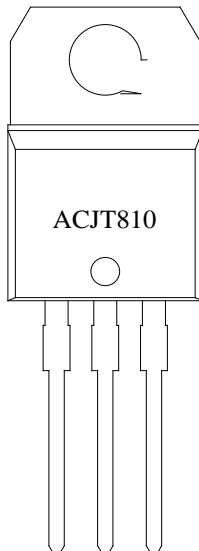




FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards





**ACJT810-10A**

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